



PNP MEDIUM POWER TRANSISTORS IN SOT89

Features

- BV_{CEO} > -45V, -60V & -80V
- I_C = -1A Continuous Collector Current
- I_{CM} = -2A Peak Pulse Current
- Low Saturation Voltage V_{CE(sat)} < -500mV @ -0.5A
- Gain Groups 10 and 16
- Complementary NPN Types: BCX54, 55, and 56
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen- and Antimony-Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative. https://www.diodes.com/quality/product-definitions/

Mechanical Data

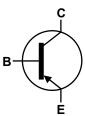
- Case: SOT89
- Case Material: Molded Plastic, "Green" Molding Compound;
 UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish Leads; Solderable per MIL-STD-202 Method 208 (3)
- Weight: 0.052 grams (Approximate)

Applications

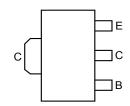
- Medium Power Switching or Amplification Applications
- AF Driver and Output Stages







Device Symbol



Top View Pin-Out

Ordering Information (Note 4)

Product	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
BCX51TA	Standard	AA	7	12	1,000
BCX51-13R	Standard	AA	13	12	4,000
BCX5110TA	Standard	AC	7	12	1,000
BCX5116TA	Standard	AD	7	12	1,000
BCX5116TC	Standard	AD	13	12	4,000
BCX52TA	Standard	AE	7	12	1,000
BCX5210TA	Standard	AG	7	12	1,000
BCX5216TA	Standard	AM	7	12	1,000
BCX53TA	Standard	AH	7	12	1,000
BCX5310TA	Standard	AK	7	12	1,000
BCX5316TA	Standard	AL	7	12	1,000
BCX5316TC	Standard	AL	13	12	4,000
BCX5316-13R	Standard	AL	13	12	4,000
BCX5110TC	Standard	AC	13	12	4,000
BCX51TC	Standard	AA	13	12	4,000
BCX5210TC	Standard	AG	13	12	4,000
BCX5216TC	Standard	AM	13	12	4,000
BCX52TC	Standard	AE	13	12	4,000
BCX5310TC	Standard	AK	13	12	4,000
BCX53TC	Standard	AH	13	12	4,000

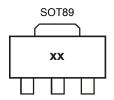
Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

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Marking Information



xx = Product Type Marking Code, as follows:

BCX51 = AA BCX52 = AE BCX53 = AH BCX5110 = AC BCX5210 = AG BCX5310 = AK BCX5116 = AD BCX5216 = AM BCX5316 = AL

Absolute Maximum Ratings (@ TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	BCX51	BCX52	BCX53	Unit
Collector-Base Voltage	V_{CBO}	-45	-60	-100	V
Collector-Emitter Voltage	V_{CEO}	-45	-60	-80	V
Emitter-Base Voltage	V _{EBO}		-5		
Continuous Collector Current	Ic		-1		
Peak Pulse Collector Current (Single pulse)	I _{CM}		-2		
Continuous Base Current	I _B		-100		
Peak Pulse Base Current (Single pulse)	I _{BM}	-200			mA

Thermal Characteristics (@ T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
	(Note 5)		1		
Power Dissipation	(Note 6)	P_{D}	1.5	W	
	(Note 7)		2.0		
	(Note 5)		125	°C/W	
Thermal Resistance, Junction to Ambient Air	(Note 6)	$R_{ heta JA}$	83		
	(Note 7)		60		
Thermal Resistance, Junction to Lead	(Note 8)	$R_{ heta JL}$	13	°C/W	
Thermal Resistance, Junction to Case (Note 9)		R _{θJC}	27	°C/W	
Operating and Storage Temperature Range	T _{J,} T _{STG}	-55 to +150	°C		

ESD Ratings (Note 10)

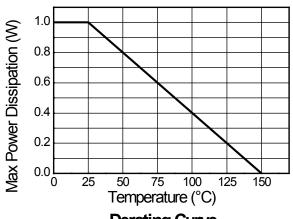
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

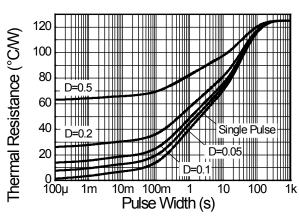
Notes: 5. For a device mounted with the exposed collector pad on 15mm x 15mm 1oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.

- 6. Same as Note 5, except the device is mounted on 25mm x 25mm 1oz copper.
- 7. Same as Note 5, except the device is mounted on 50mm x 50mm 1oz copper.
- 8. Thermal resistance from junction to solder-point (on the exposed collector pad).
- 9. Thermal resistance from junction to the top of the case.
- 10. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



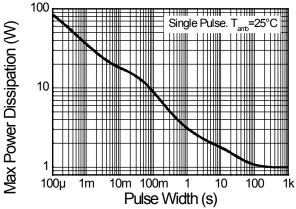
Thermal Characteristics and Derating Information



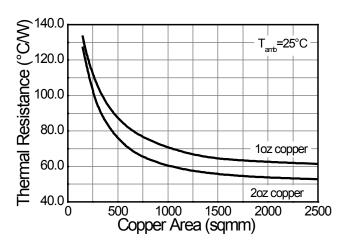


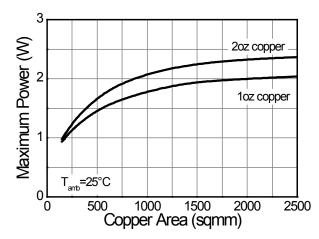
Derating Curve

Transient Thermal Impedance



Pulse Power Dissipation







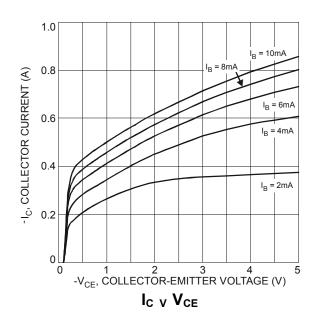
Electrical Characteristics (@ T_A = +25°C, unless otherwise specified.)

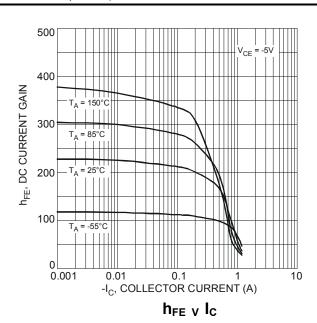
Characteristic		Symbol	Min	Тур	Max	Unit	Test Condition
Calleston Base	BCX51		-45				
Collector-Base Breakdown Voltage	BCX52	BV_CBO	-60	_	_	V	$I_C = -100 \mu A$
Breakdown voltage	BCX53		-100				
Collector-Emitter	BCX51		-45				
Breakdown Voltage (Note 11)	BCX52	BV _{CEO}	-60	_	_	V	I _C = -10mA
Breakdown Voltage (Note 11)	BCX53		-80				
Emitter-Base Breakdown Voltage		BV _{EBO}	-5	_	_	V	$I_E = -10\mu A$
Collector Cut-Off Current		I _{CBO}	_	_	-0.1 -20	μA	V _{CB} = -30V
Collector Cut-Off Current							$V_{CB} = -30V, T_J = +150^{\circ}C$
Emitter Cut-Off Current		I _{EBO}		_	-20	nA	V _{EB} = -5V
	All versions		25	_	_		$I_C = -5mA, V_{CE} = -2V$
		h _{FE}	40	_	250	_	$I_C = -150 \text{mA}, V_{CE} = -2 \text{V}$
DC Current Gain (Note 11)			25	_	_		$I_C = -500 \text{mA}, V_{CE} = -2 \text{V}$
	10 gain grp		63	_	160		$I_C = -150 \text{mA}, V_{CE} = -2 \text{V}$
	16 gain grp		100	_	250		$I_C = -150 \text{mA}, V_{CE} = -2 \text{V}$
Collector-Emitter Saturation Voltage (Note 11)		V _{CE(sat)}	-	_	-0.5	V	$I_C = -500 \text{mA}, I_B = -50 \text{mA}$
Base-Emitter Turn-On Voltage (Note 11)		V _{BE(on)}	-	_	-1.0	V	$I_C = -500 \text{mA}, V_{CE} = -2 \text{V}$
Transition frequency		f⊤	150	_	_	MHz	I _C = -50mA, V _{CE} = -10V f = 100MHz
Output Capacitance		Cobo	_	_	25	pF	V _{CB} = -10V, f = 1MHz

Note:

11. Measured under pulsed conditions. Pulse width ≤ 300µs. Duty cycle ≤ 2%.

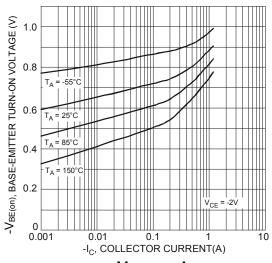
Typical Electrical Characteristics (@ T_A = +25°C, unless otherwise specified.)



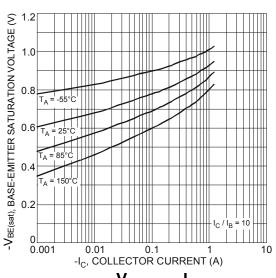




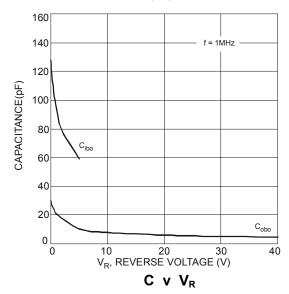
Typical Electrical Characteristics (continued.)

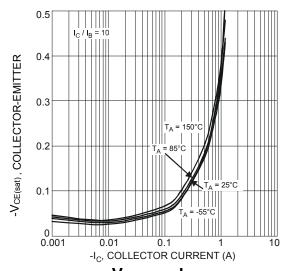


$V_{\text{BE(on)}} \ V \ I_{\text{C}}$

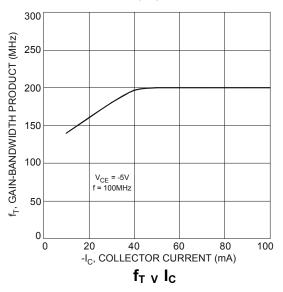


V_{BE(sat)} v I_C





V_{CE(sat)} _V I_C

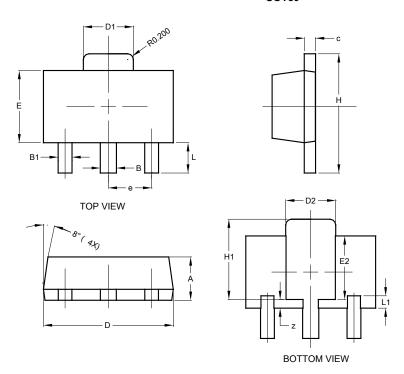




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT89

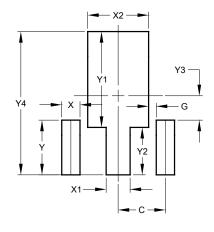


SOT89						
Dim	Min	Max	Тур			
Α	1.40	1.60	1.50			
В	0.50	0.62	0.56			
B1	0.42	0.54	0.48			
C	0.35	0.43	0.38			
D	4.40	4.60	4.50			
D1	1.62	1.83	1.733			
D2	1.61	1.81	1.71			
Е	2.40	2.60	2.50			
E2	2.05	2.35	2.20			
e	-	1	1.50			
Η	3.95	4.25	4.10			
H1	2.63	2.93	2.78			
L	0.90	1.20	1.05			
L1	0.327	0.527	0.427			
Z	0.20	0.40	0.30			
All Dimensions in mm						

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT89



Dimensions	value		
פווטופווסוטווס	(in mm)		
C	1.500		
G	0.244		
X	0.580		
X1	0.760		
X2	1.933		
Y	1.730		
Y1	3.030		
Y2	1.500		
Y3	0.770		
Y4	4.530		



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